



# PJS6815

## 20V P-Channel Enhancement Mode MOSFET

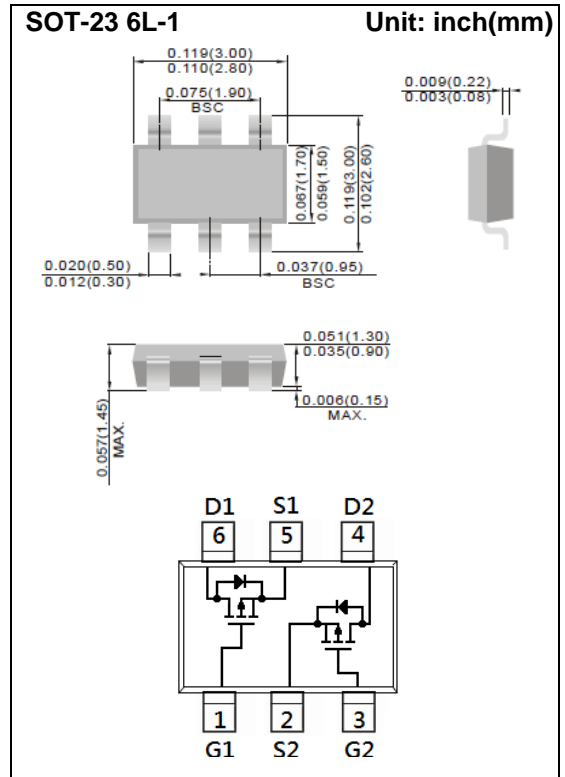
**Voltage**    **-20 V**    **Current**    **-3.6A**

### Features

- $R_{DS(ON)}$  ,  $V_{GS@-4.5V}$  ,  $I_{D@-3.6A} < 57m\Omega$
- $R_{DS(ON)}$  ,  $V_{GS@-2.5V}$  ,  $I_{D@-2.8A} < 70m\Omega$
- $R_{DS(ON)}$  ,  $V_{GS@-1.8V}$  ,  $I_{D@-2.1A} < 95m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case: SOT-23 6L-1 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams
- Marking: S15



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	$V_{DS}$	-20	V
Gate-Source Voltage	$V_{GS}$	+12	V
Continuous Drain Current	$I_D$	-3.6	A
Pulsed Drain Current	$I_{DM}$	-14.4	A
Power Dissipation	$P_D$	$T_a=25^\circ\text{C}$	1.25
		Derate above $25^\circ\text{C}$	10
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
Typical Thermal resistance	$R_{\theta JA}$	100	$^\circ\text{C/W}$
- Junction to Ambient <sup>(Note 3)</sup>			



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.4	-0.62	-1.2	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=-4.5V, I_D=-3.6A$	-	49	57	m $\Omega$
		$V_{GS}=-2.5V, I_D=-2.8A$	-	59	70	
		$V_{GS}=-1.8V, I_D=-2.1A$	-	74	95	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-20V, V_{GS}=0V$	-	-0.01	-1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$	-	$\pm 10$	$\pm 100$	nA
<b>Dynamic</b>						
Total Gate Charge	$Q_g$	$V_{DS}=-10V, I_D=-3.6A,$ $V_{GS}=-4.5V$ (Note 1,2)	-	18	-	nC
Gate-Source Charge	$Q_{gs}$		-	2.1	-	
Gate-Drain Charge	$Q_{gd}$		-	7.4	-	
Input Capacitance	$C_{iss}$	$V_{DS}=-10V, V_{GS}=0V,$ $f=1.0\text{MHZ}$	-	756	-	pF
Output Capacitance	$C_{oss}$		-	75	-	
Reverse Transfer Capacitance	$C_{rss}$		-	58	-	
<b>Switching</b>						
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-10V, I_D=-3.6A,$ $V_{GS}=-4.5V,$ $R_G=6\Omega$ (Note 1,2)	-	5	-	ns
Turn-On Rise Time	$t_r$		-	61	-	
Turn-Off Delay Time	$t_{d(off)}$		-	70	-	
Turn-Off Fall Time	$t_f$		-	137	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	-1.5	A
Diode Forward Voltage	$V_{SD}$	$I_S=-1.0A, V_{GS}=0V$	-	0.76	-1.2	V

NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited



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## TYPICAL CHARACTERISTIC CURVES

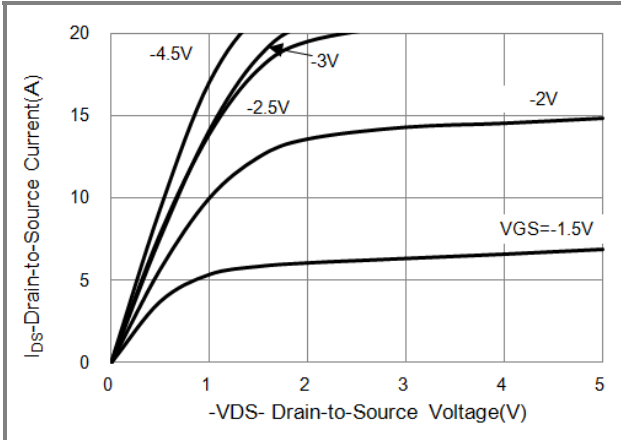


Fig.1 On-Region Characteristics

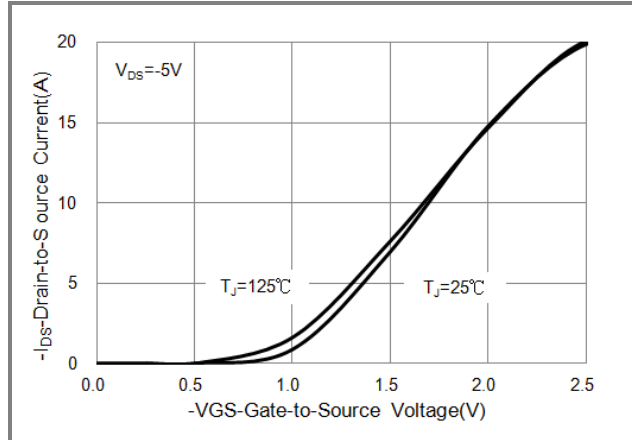


Fig.2 Transfer Characteristics

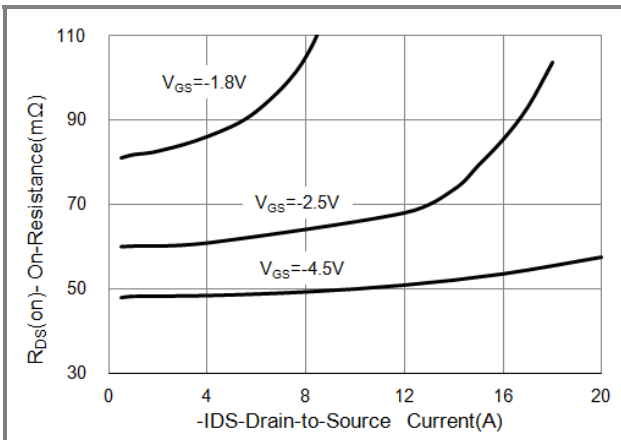


Fig.3 On-Resistance vs. Drain Current

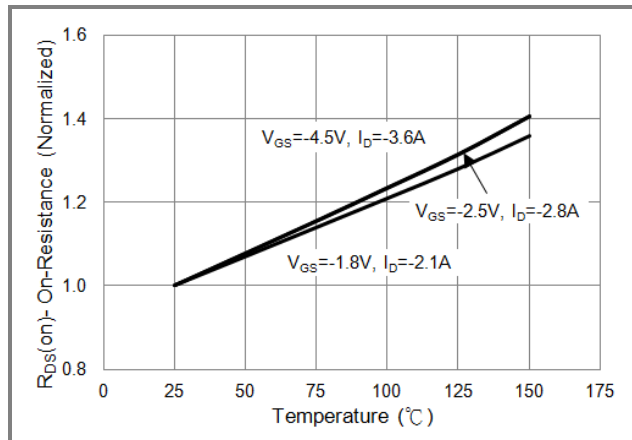


Fig.4 On-Resistance vs. Junction temperature

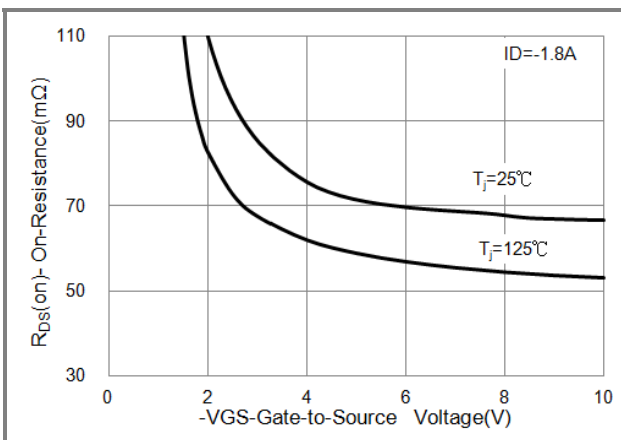


Fig.5 On-Resistance Variation with VGS.

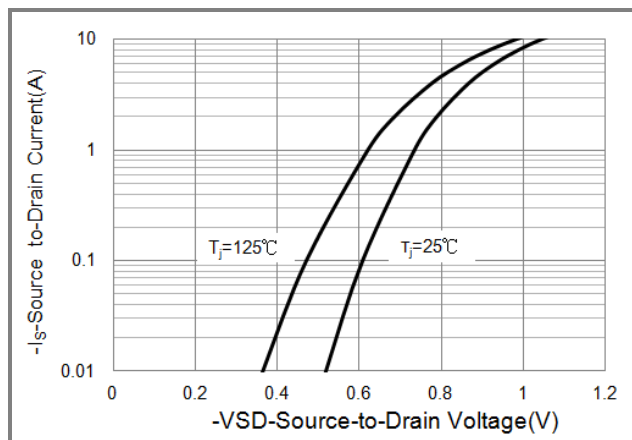


Fig.6 Body Diode Characteristics



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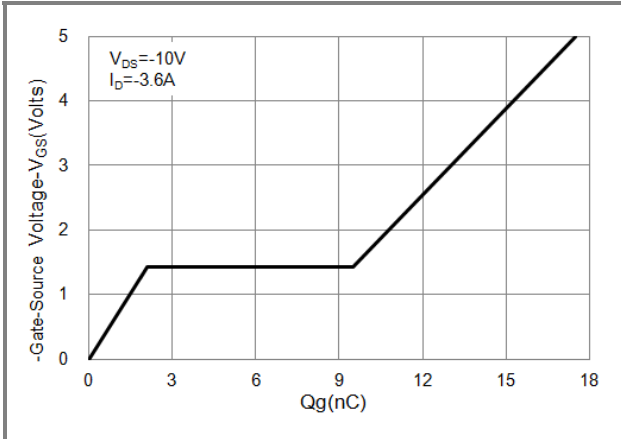


Fig.7 Gate-Charge Characteristics

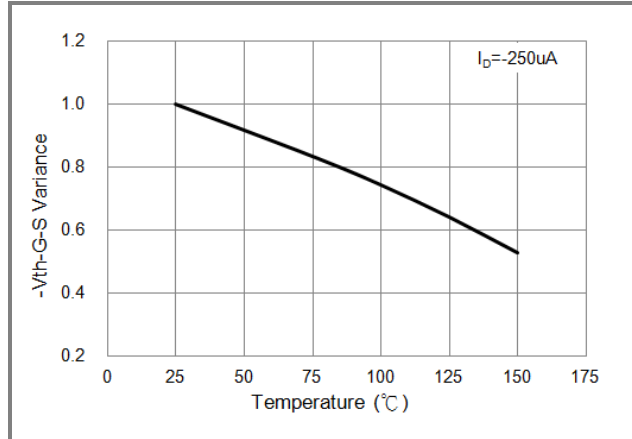


Fig.8 Threshold Voltage Variation with Temperature.

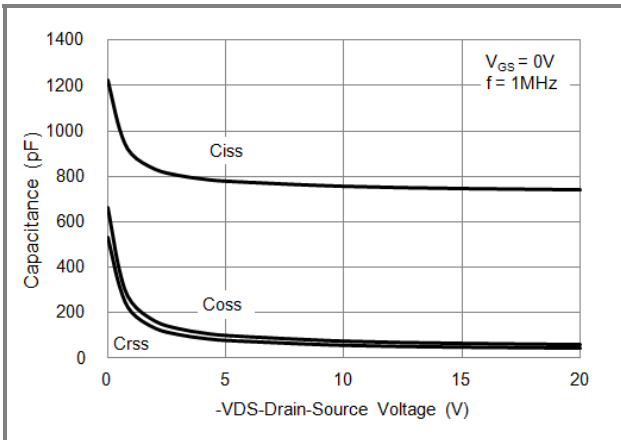


Fig.9 Capacitance vs. Drain-Source Voltage

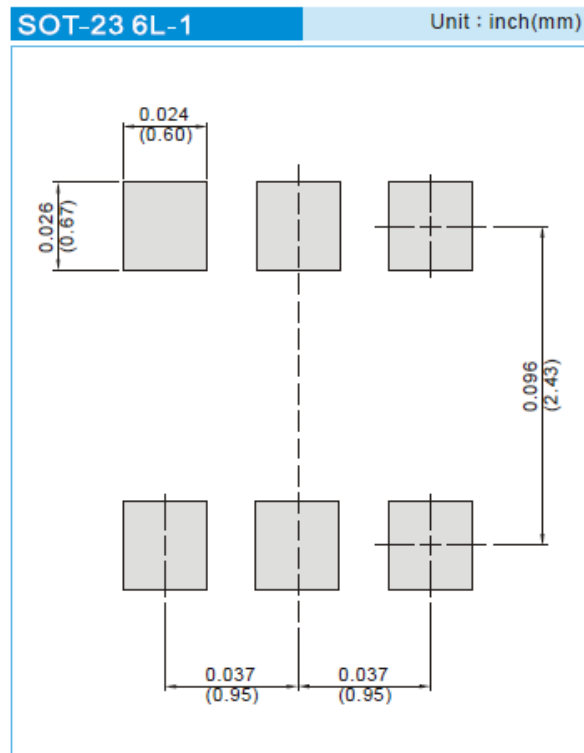


# PJS6815

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJS6815_S1_00001	SOT-23 6L-1	3K pcs / 7" reel	S15	Halogen free

## MOUNTING PAD LAYOUT





## PJS6815

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